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# FDME430NT

## N-Channel PowerTrench® MOSFET

30 V, 6 A, 40 mΩ

### Features

- Max  $r_{DS(on)}$  = 40 mΩ at  $V_{GS} = 4.5$  V,  $I_D = 6$  A
- Max  $r_{DS(on)}$  = 51 mΩ at  $V_{GS} = 2.5$  V,  $I_D = 5$  A
- Max  $r_{DS(on)}$  = 71 mΩ at  $V_{GS} = 1.8$  V,  $I_D = 4$  A
- Low profile: 0.55 mm maximum in the new package MicroFET 1.6x1.6 Thin
- Free from halogenated compounds and antimony oxides
- RoHS Compliant

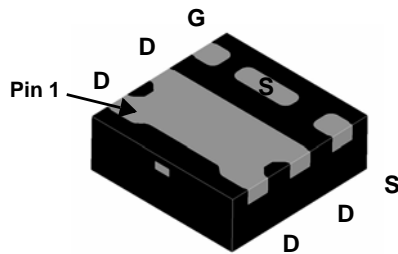


### General Description

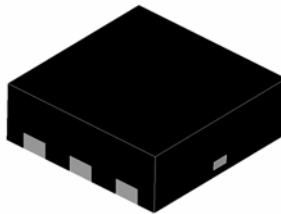
This single N-Channel MOSFET has been designed using Fairchild Semiconductor's advanced PowerTrench® process to optimize the  $r_{DS(ON)}$  @  $V_{GS} = 1.8$  V on special MicroFET leadframe.

### Applications

- Li-Ion Battery Pack
- Baseband Switch
- Load Switch
- DC-DC Conversion

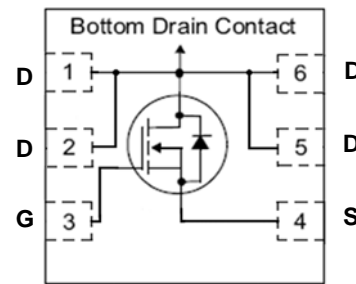


BOTTOM



TOP

MicroFET 1.6x1.6 Thin



### MOSFET Maximum Ratings $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Rated	Units
$V_{DS}$	Drain to Source Voltage	30	V
$V_{GS}$	Gate to Source Voltage	±12	V
$I_D$	Drain Current -Continuous $T_A = 25$ °C (Note 1a)	6	A
	-Pulsed	30	
$P_D$	Power Dissipation for Single Operation $T_A = 25$ °C (Note 1a)	2.1	W
	Power Dissipation for Single Operation $T_A = 25$ °C (Note 1b)	0.7	
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range	-55 to +150	°C

### Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	60	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	175	

### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
YA	FDME430NT	MicroFET 1.6x1.6 Thin	7"	8 mm	5000 units

## Electrical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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### Off Characteristics

$BV_{DSS}$	Drain to Source Breakdown Voltage	$I_D = 250\text{ }\mu\text{A}$ , $V_{GS} = 0\text{ V}$	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250\text{ }\mu\text{A}$ , referenced to $25\text{ }^\circ\text{C}$		22		mV/ $^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 24\text{ V}$ , $V_{GS} = 0\text{ V}$			1	$\mu\text{A}$
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 12\text{ V}$ , $V_{DS} = 0\text{ V}$			$\pm 100$	nA

### On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 250\text{ }\mu\text{A}$	0.6	0.8	1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250\text{ }\mu\text{A}$ , referenced to $25\text{ }^\circ\text{C}$		-3		mV/ $^\circ\text{C}$
$r_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = 4.5\text{ V}$ , $I_D = 6\text{ A}$		25	40	m $\Omega$
		$V_{GS} = 2.5\text{ V}$ , $I_D = 5\text{ A}$		29	51	
		$V_{GS} = 1.8\text{ V}$ , $I_D = 4\text{ A}$		38	71	
		$V_{GS} = 4.5\text{ V}$ , $I_D = 6\text{ A}$ , $T_J = 125\text{ }^\circ\text{C}$		34	54	
$g_{FS}$	Forward Transconductance	$V_{DS} = 5\text{ V}$ , $I_D = 6\text{ A}$		31		S

### Dynamic Characteristics

$C_{iss}$	Input Capacitance	$V_{DS} = 15\text{ V}$ , $V_{GS} = 0\text{ V}$ , $f = 1\text{ MHz}$		572	760	pF
$C_{oss}$	Output Capacitance			74	100	pF
$C_{rss}$	Reverse Transfer Capacitance			51	75	pF

### Switching Characteristics

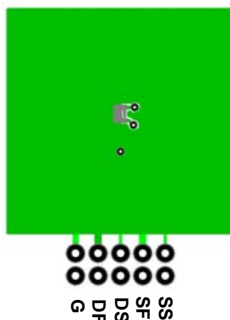
$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 15\text{ V}$ , $I_D = 6\text{ A}$ , $V_{GS} = 4.5\text{ V}$ , $R_{GEN} = 6\text{ }\Omega$		7	14	ns
$t_r$	Rise Time			3	10	ns
$t_{d(off)}$	Turn-Off Delay Time			19	34	ns
$t_f$	Fall Time			3.3	10	ns
$Q_g$	Total Gate Charge	$V_{DD} = 15\text{ V}$ , $I_D = 6\text{ A}$ , $V_{GS} = 4.5\text{ V}$		6.5	9	nC
$Q_{gs}$	Gate to Source Gate Charge			0.9		nC
$Q_{gd}$	Gate to Drain "Miller" Charge			1.6		nC

### Drain-Source Diode Characteristics

$V_{SD}$	Source to Drain Diode Forward Voltage	$V_{GS} = 0\text{ V}$ , $I_S = 6\text{ A}$ (Note 2)		0.8	1.2	V
		$V_{GS} = 0\text{ V}$ , $I_S = 1.6\text{ A}$ (Note 2)		0.7	1.2	V
$t_{rr}$	Reverse Recovery Time	$I_F = 6\text{ A}$ , $di/dt = 100\text{ A}/\mu\text{s}$		12	22	ns
$Q_{rr}$	Reverse Recovery Charge			2.9	10	nC

#### Notes:

- $R_{\theta JA}$  is determined with the device mounted on a  $1\text{ in}^2$  pad 2 oz copper pad on a  $1.5 \times 1.5\text{ in.}$  board of FR-4 material.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.



a.  $60\text{ }^\circ\text{C}/\text{W}$  when mounted on a  $1\text{ in}^2$  pad of 2 oz copper.



b.  $175\text{ }^\circ\text{C}/\text{W}$  when mounted on a minimum pad of 2 oz copper.

- Pulse Test: Pulse Width <  $300\text{ }\mu\text{s}$ , Duty cycle < 2.0%.

**Typical Characteristics**  $T_J = 25\text{ }^\circ\text{C}$  unless otherwise noted

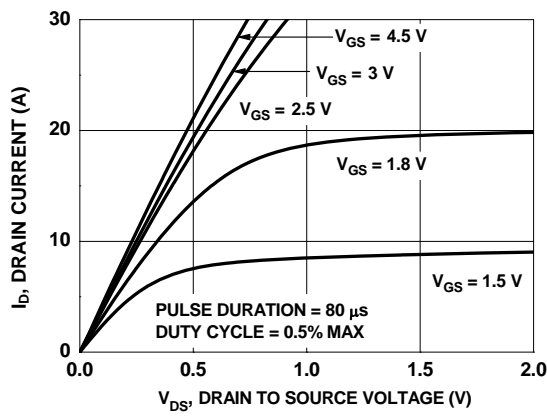


Figure 1. On Region Characteristics

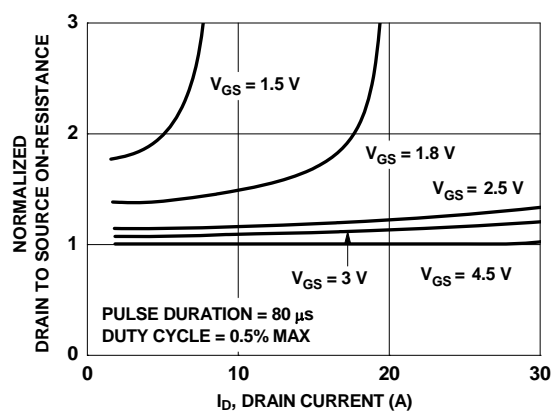


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

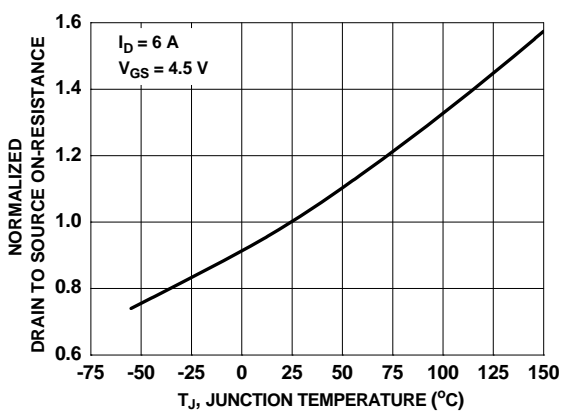


Figure 3. Normalized On Resistance vs Junction Temperature

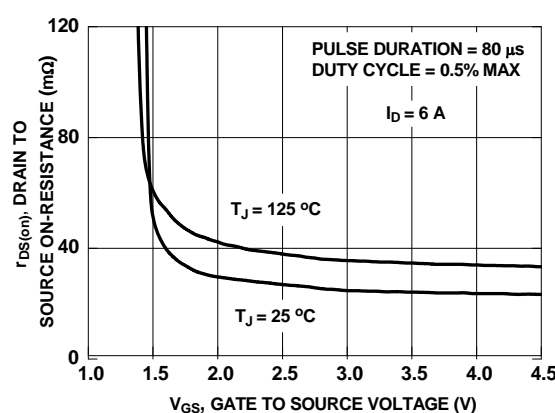


Figure 4. On-Resistance vs Gate to Source Voltage

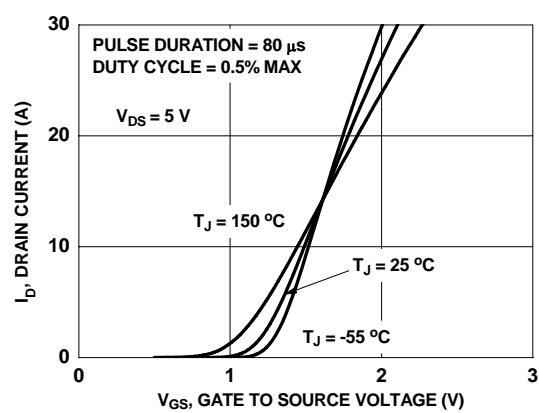


Figure 5. Transfer Characteristics

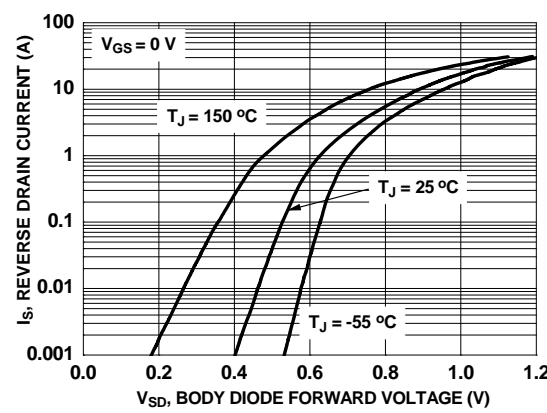
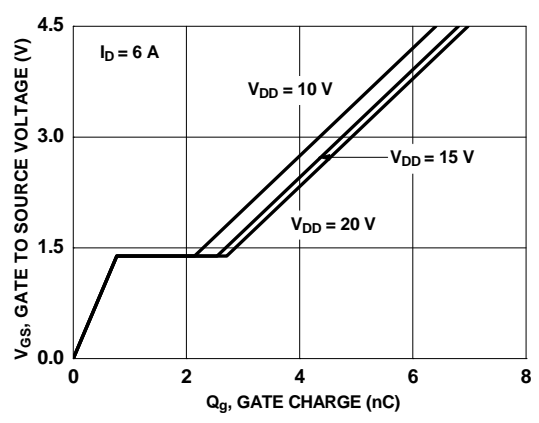
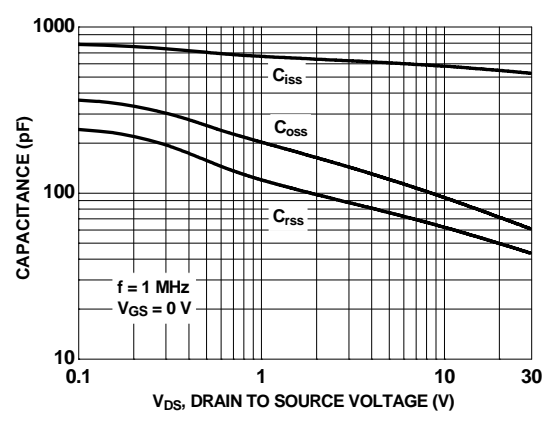


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

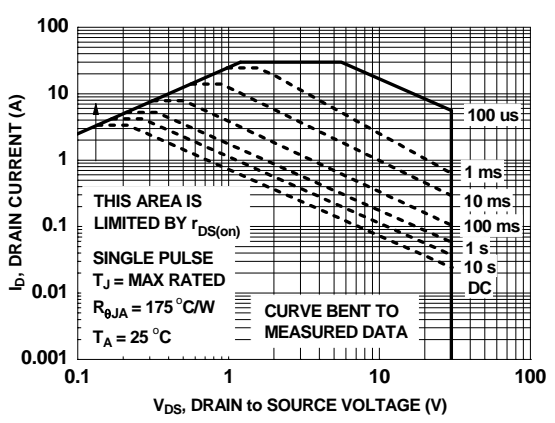
**Typical Characteristics**  $T_J = 25\text{ }^\circ\text{C}$  unless otherwise noted



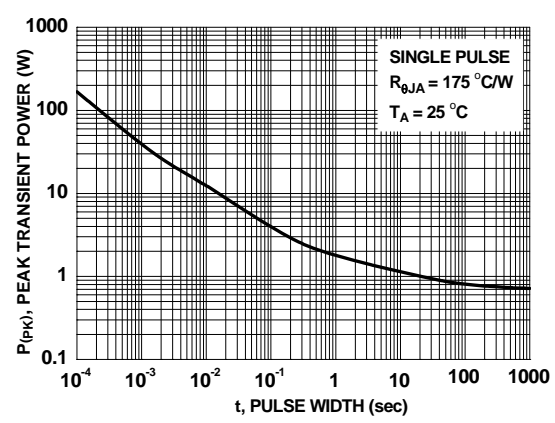
**Figure 7. Gate Charge Characteristics**



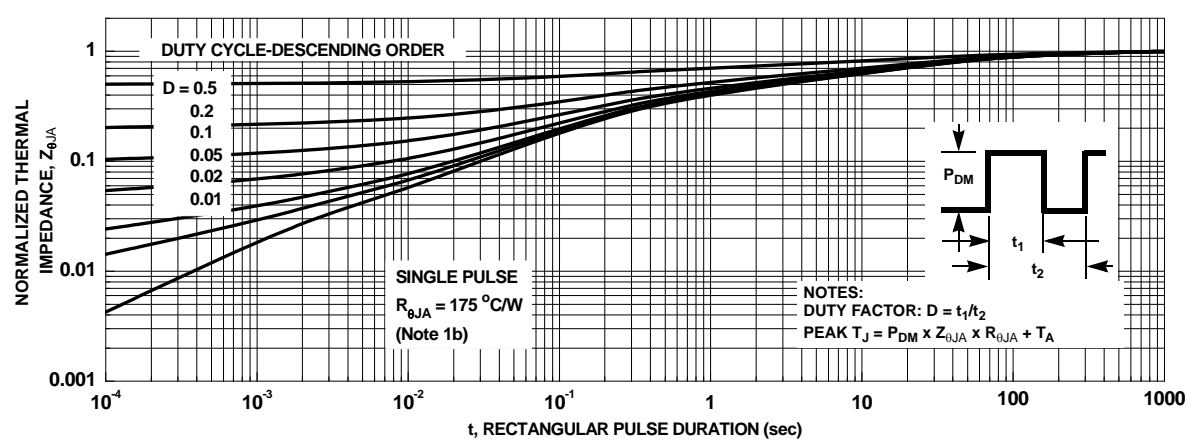
**Figure 8. Capacitance vs Drain to Source Voltage**



**Figure 9. Forward Bias Safe Operating Area**

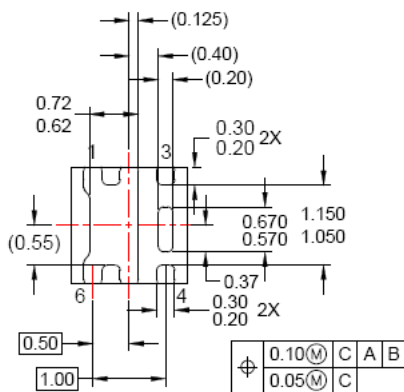
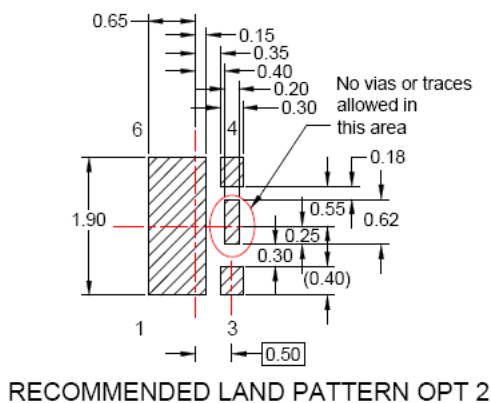
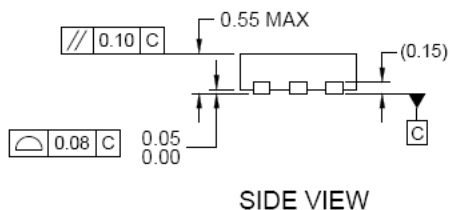
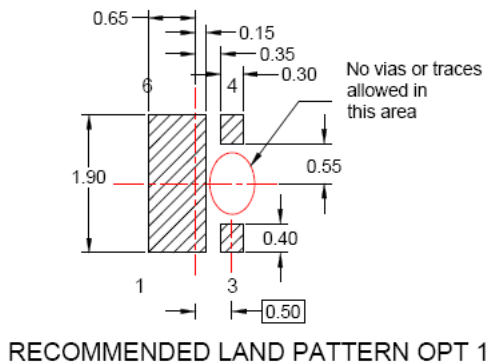
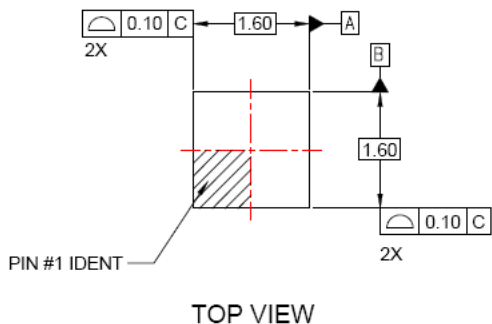


**Figure 10. Single Pulse Maximum Power Dissipation**



**Figure 11. Junction-to-Ambient Transient Thermal Response Curve**

### Dimensional Outline and Pad Layout





- NOTES:
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  - B. DIMENSIONS ARE IN MILLIMETERS.
  - C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
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